

SEMICONDUCTOR DEVICE, AND MANUFACTURING METHOD THEREOF

ABSTRACT OF THE DISCLOSURE

5 In a display device such as a liquid crystal display device, a large-sized display screen
is realized under low power consumption. A surface of a source wiring line of a pixel
portion
employed in an active matrix type liquid crystal display device is processed by way of a
10 plating process operation so as to lower a resistance value of this source wiring line. The
source wiring line of the pixel portion is manufactured at a step different from a step for
manufacturing a source wiring line of a drive circuit portion. Further, electrodes of a
terminal portion are processed by a plating process operation so as to reduce a resistance
value thereof.

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Figure 7B